

**TRIAC(Through Hole / Isolated)****TMG3C80F**

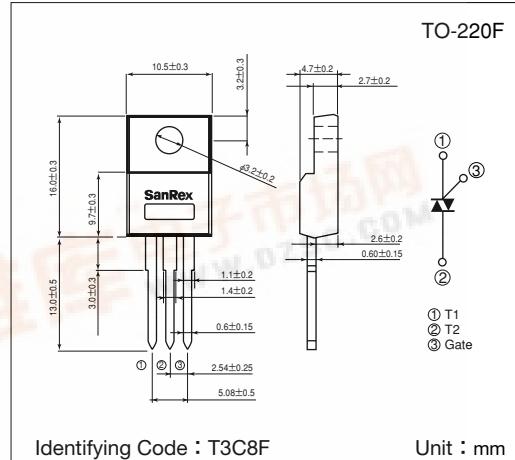
**SanRex** Triac TMG3C80F is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

**Typical Applications**

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

**Features**

- $I_{T(RMS)}=3A$
- High Surge Current
- Low Voltage Drop
- Lead-Free Package

**Maximum Ratings**(T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Item	Reference	Ratings		Unit
V <sub>DRM</sub>	Repetitive Peak Off-State Voltage		800		V
I <sub>T(RMS)</sub>	R.M.S. On-State Current	T <sub>c</sub> =107°C	3		A
I <sub>SM</sub>	Surge On-State Current	One cycle, 50Hz/60Hz, Peak value non-repetitive	27/30		A
I <sup>t</sup>	I <sup>t</sup> (for fusing)		3.7		A°S
P <sub>GM</sub>	Peak Gate Power Dissipation		1.5		W
P <sub>G(AV)</sub>	Average Gate Power Dissipation		0.1		W
I <sub>GM</sub>	Peak Gate Current		1		A
V <sub>GM</sub>	Peak Gate Voltage		7		V
V <sub>ISO</sub>	Isolation Breakdown Voltage (R.M.S.)	A.C. 1 minute	1500		V
T <sub>j</sub>	Operating Junction Temperature		-40~+125		°C
T <sub>STG</sub>	Storage Temperature		-40~+150		°C
	Mass		2		g

**Electrical Characteristics**

Symbol	Item	Reference	Ratings			Unit
			Min.	Typ.	Max.	
I <sub>DRM</sub>	Repetitive Peak Off-State Current	V <sub>D</sub> =V <sub>DRM</sub> , Single phase, half wave, T <sub>j</sub> =125°C			1	mA
V <sub>TM</sub>	Peak On-State Voltage	I <sub>T</sub> =4.5A, Inst. measurement			1.4	V
I <sub>GT1</sub> <sup>+</sup> 1	Gate Trigger Current	V <sub>D</sub> =6V, R <sub>L</sub> =10Ω			15	mA
I <sub>GT1</sub> <sup>-</sup> 2					15	
I <sub>GT3</sub> <sup>+</sup> 3					—	
I <sub>GT3</sub> <sup>-</sup> 4					15	
V <sub>GT1</sub> <sup>+</sup> 1	Gate Trigger Voltage				1.5	V
V <sub>GT1</sub> <sup>-</sup> 2					1.5	
V <sub>GT3</sub> <sup>+</sup> 3					—	
V <sub>GT3</sub> <sup>-</sup> 4					1.5	
V <sub>GD</sub>	Non-Trigger Gate Voltage	T <sub>j</sub> =125°C, V <sub>D</sub> =1/2V <sub>DRM</sub>	0.2			V
[dv/dt] <sub>C</sub>	Critical Rate of Rise of Off-State Voltage at Commutation	T <sub>j</sub> =125°C, [di/dt] <sub>C</sub> =-1.5A/ms, V <sub>D</sub> =400V	5			V/μs
I <sub>H</sub>	Holding Current			2		mA
R <sub>th(j-c)</sub>	Thermal Resistance	Junction to case			5	°C/W

Trigger mode of the triac

